

## N-Channel Super Junction Power MOSFET $\, III \,$

## **General Description**

The series of devices use advanced trench gate super junction technology and design to provide excellent R<sub>DS(ON)</sub> with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

### Features

- •New technology for high voltage device
- •Low on-resistance and low conduction losses
- Small package
- ●Ultra Low Gate Charge cause lower driving requirements
- ●100% Avalanche Tested
- ●ROHS compliant

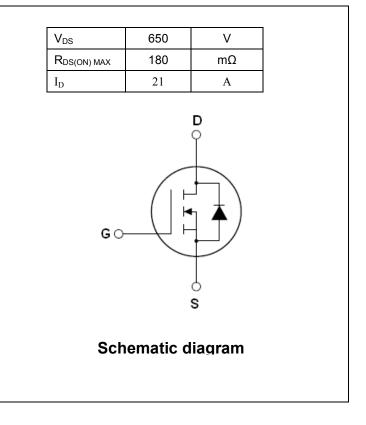
## Application

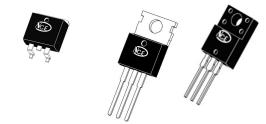
- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)

#### Package Marking And Ordering Information

| Device     | Device Package | Marking    |
|------------|----------------|------------|
| NCE65T180  | TO-220         | NCE65T180  |
| NCE65T180F | TO-220F        | NCE65T180F |
| NCE65T180D | TO-263         | NCE65T180  |

### Table 1. Absolute Maximum Ratings (T<sub>c</sub>=25℃)





TO-263

TO-220

TO-220F

| Parameter   | Symbol                  | NCE65T180<br>NCE65T180D | NCE65T180F | Unit |
|---|-------------------------|-------------------------|------------|------|
| Drain-Source Voltage (V <sub>GS</sub> =0V)                            | Vds                     | 65                      | 50         | V    |
| Gate-Source Voltage (VDs=0V), AC (f>1 Hz)                             | Vgs                     | ±30                     |            | V    |
| Continuous Drain Current at T <sub>C</sub> =25°C                      | I <sub>D (DC)</sub>     | 21                      | 21*        | А    |
| Continuous Drain Current at T <sub>C</sub> =100°C                     | I <sub>D (DC)</sub>     | 13.2                    | 13.2*      | А    |
| Pulsed drain current (Note 1)   | I <sub>DM (pluse)</sub> | 84                      | 84*        | А    |
| Maximum Power Dissipation(T <sub>C</sub> =25°C)                       | PD                      | 188                     | 33.8       | W    |
| Derate above 25°C   |                         | 1.5                     | 0.27       | W/°C |
| Single pulse avalanche energy (Note 2)                                | Eas                     | 441                     |            | mJ   |
| Avalanche current <sup>(Note 1)</sup>                                 | I <sub>AR</sub>         | 10.5                    |            | А    |
| Repetitive Avalanche energy , $t_{AR}$ limited by $T_{Jmax}$ (Note 1) | E <sub>AR</sub>         | 0.7                     |            | mJ   |



## NCE65T180D,NCE65T180,NCE65T180F

| Parameter   | Symbol         | NCE65T180<br>NCE65T180D | NCE65T180F | Unit |
|---|----------------|-------------------------|------------|------|
| Drain Source voltage slope, $V_{DS} \leqslant 480 V$ ,      | dv/dt          | 5                       | 0          | V/ns |
| Reverse diode dv/dt, $V_{DS} \leqslant 480 V, I_{SD} < I_D$ | dv/dt          | 1                       | 5          | V/ns |
| Operating Junction and Storage Temperature Range            | $T_J, T_{STG}$ | -55                     | +150       | °C   |

\* limited by maximum junction temperature

### Table 2. Thermal Characteristic

| Parameter   | Symbol            | NCE65T180<br>NCE65T180D | NCE65T180F | Unit  |
|---|-------------------|-------------------------|------------|-------|
| Thermal Resistance, Junction-to-Case (Maximum)    | R <sub>thJC</sub> | 0.66                    | 3.69       | °C /W |
| Thermal Resistance, Junction-to-Ambient (Maximum) | R <sub>thJA</sub> | 62.5                    | 80         | °C /W |

## Table 3. Electrical Characteristics (TA=25 $^\circ\!\!\mathrm{C}$ unless otherwise noted)

| Parameter                                | Symbol              | Condition   | Min | Тур  | Мах  | Unit |  |
|--|---------------------|---|-----|------|------|------|--|
| On/off states                            |                     |   |     |      |      |      |  |
| Drain-Source Breakdown Voltage           | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V I <sub>D</sub> =250µA               | 650 |      |      | V    |  |
| Zero Gate Voltage Drain Current(Tc=25°C) | I <sub>DSS</sub>    | V <sub>DS</sub> =650V,V <sub>GS</sub> =0V               |     | 0.05 | 1    | μA   |  |
| Zero Gate Voltage Drain Current(Tc=125℃) | I <sub>DSS</sub>    | V <sub>DS</sub> =650V,V <sub>GS</sub> =0V               |     |      | 100  | μA   |  |
| Gate-Body Leakage Current                | I <sub>GSS</sub>    | V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V               |     |      | ±100 | nA   |  |
| Gate Threshold Voltage                   | V <sub>GS(th)</sub> | V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA | 3   | 3.5  | 4    | V    |  |
| Drain-Source On-State Resistance         | R <sub>DS(ON)</sub> | V <sub>GS</sub> =10V, I <sub>D</sub> =10.5A             |     | 150  | 180  | mΩ   |  |
| Dynamic Characteristics                  |                     |   |     |      |      |      |  |
| Forward Transconductance                 | <b>g</b> fs         | V <sub>DS</sub> = 20V, I <sub>D</sub> = 10.5A           |     | 16   |      | S    |  |
| Input Capacitance                        | C <sub>lss</sub>    |   |     | 2250 |      | PF   |  |
| Output Capacitance                       | C <sub>oss</sub>    | V <sub>DS</sub> =50V,V <sub>GS</sub> =0V,<br>F=1.0MHz   |     | 83   |      | PF   |  |
| Reverse Transfer Capacitance             | Crss                |   |     | 1.6  |      | PF   |  |
| Total Gate Charge                        | Qg                  | V 400V/L 04A  |     | 36   |      | nC   |  |
| Gate-Source Charge                       | Q <sub>gs</sub>     | V <sub>DS</sub> =480V,I <sub>D</sub> =21A,              |     | 14   |      | nC   |  |
| Gate-Drain Charge                        | Q <sub>gd</sub>     | V <sub>GS</sub> =10V                                    |     | 8.5  |      | nC   |  |
| Switching times                          |                     |   |     |      |      |      |  |
| Turn-on Delay Time                       | t <sub>d(on)</sub>  |   |     | 11   |      | nS   |  |
| Turn-on Rise Time                        | tr                  | V <sub>DD</sub> =380V,I <sub>D</sub> =11A,              |     | 6    |      | nS   |  |
| Turn-Off Delay Time                      | t <sub>d(off)</sub> | R <sub>G</sub> =4Ω,V <sub>GS</sub> =10V                 |     | 61   |      | nS   |  |
| Turn-Off Fall Time                       | t <sub>f</sub>      |   |     | 4.5  |      | nS   |  |
| Source- Drain Diode Characteristics      |                     |   |     |      |      |      |  |
| Source-drain current(Body Diode)         | I <sub>SD</sub>     | - T <sub>c</sub> =25°C                                  |     |      | 21   | А    |  |
| Pulsed Source-drain current(Body Diode)  | I <sub>SDM</sub>    | 1 <sub>C</sub> =25 C                                    |     |      | 84   | А    |  |
| Forward on voltage                       | V <sub>SD</sub>     | Tj=25°C,I <sub>SD</sub> =21A,V <sub>GS</sub> =0V        |     | 0.9  | 1.3  | V    |  |
| Reverse Recovery Time                    | t <sub>rr</sub>     |   |     | 310  |      | nS   |  |
| Reverse Recovery Charge                  | Qrr                 | T <sub>j</sub> =25°C,I <sub>F</sub> =21A,di/dt=100A/μs  |     | 5    |      | uC   |  |
| Peak Reverse Recovery Current            | Irrm                | ]   |     | 28   |      | А    |  |

Notes 1. Repetitive Rating: Pulse width limited by maximum junction temperature

 $\textbf{2. } \textbf{T}_{j} \texttt{=} \texttt{25}^{\circ} \textbf{C}, \textbf{V}_{\text{DD}} \texttt{=} \texttt{50} \textbf{V}, \textbf{V}_{\text{G}} \texttt{=} \texttt{10} \textbf{V}, \textbf{R}_{\text{G}} \texttt{=} \texttt{25} \Omega$ 



## **TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)**

Figure1. Safe operating area for TO-220/TO-263

#### Figure2. Safe operating area for TO-220F

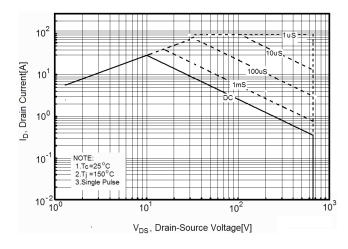


Figure3. Source-Drain Diode Forward Voltage

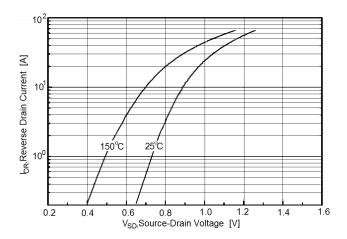
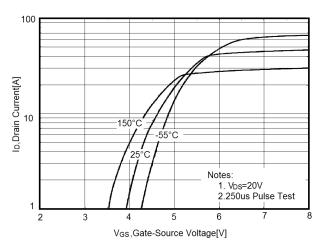


Figure5. Transfer characteristics



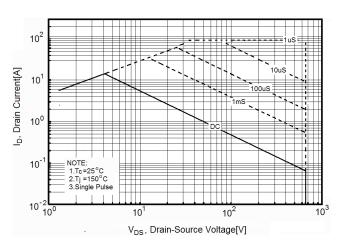


Figure4. Output characteristics

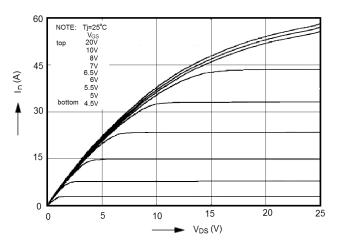


Figure6. Static drain-source on resistance

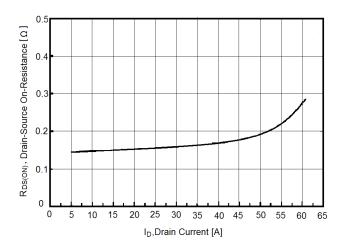




Figure7. R<sub>DS(ON)</sub> vs Junction Temperature

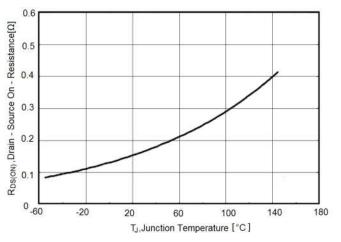


Figure8. BV<sub>DSS</sub> vs Junction Temperature

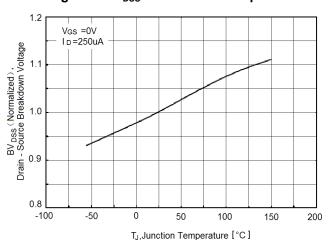


Figure9. Maximum  $I_D$  vs Junction Temperature

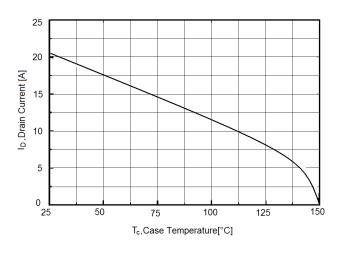


Figure10. Transient Thermal Impedance for TO-220

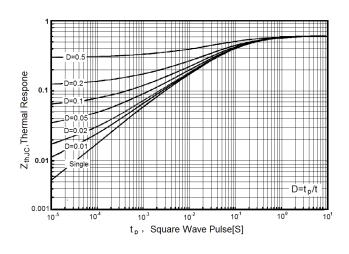


Figure11. Transient Thermal Impedance for TO-220F

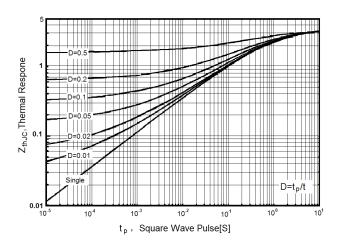
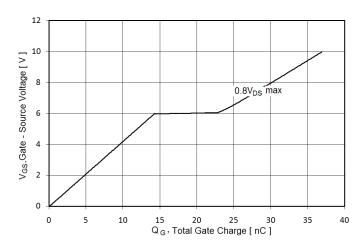
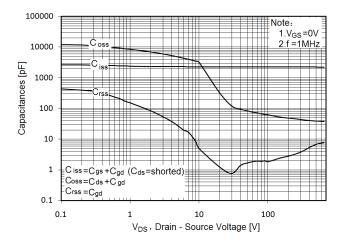


Figure12. Gate charge waveforms





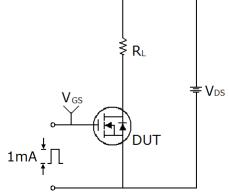
#### Figure13. Capacitance

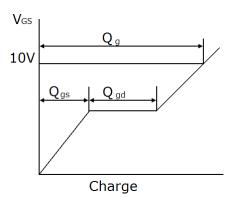




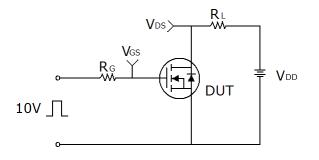
## Test circuit

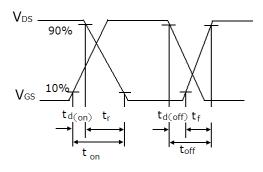
1) Gate charge test circuit & Waveform



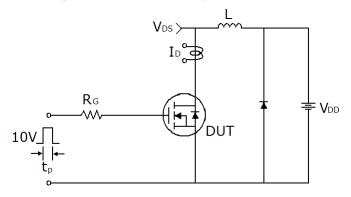


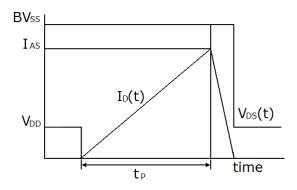
2) Switch Time Test Circuit:





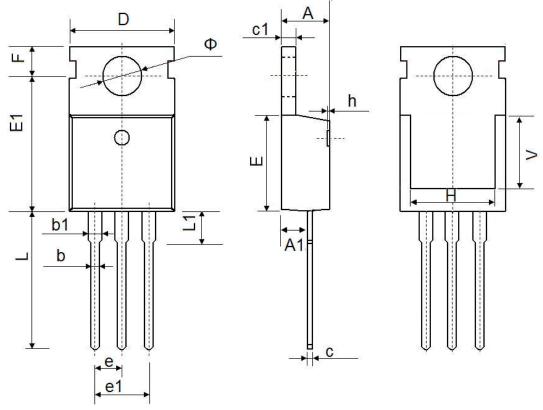
3) Unclamped Inductive Switching Test Circuit & Waveforms







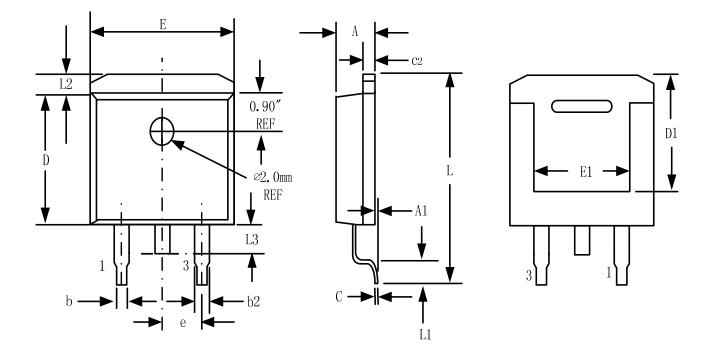
# **TO-220-3L-C Package Information**



| Cumhal | Dimensions | In Millimeters | Dimensions In Inches |       |  |
|--------|------------|----------------|----------------------|-------|--|
| Symbol | Min.       | Max.           | Min.                 | Max.  |  |
| А      | 4.400      | 4.600          | 0.173                | 0.181 |  |
| A1     | 2.250      | 2.550          | 0.089                | 0.100 |  |
| b      | 0.710      | 0.910          | 0.028                | 0.036 |  |
| b1     | 1.170      | 1.370          | 0.046                | 0.054 |  |
| С      | 0.330      | 0.650          | 0.013                | 0.026 |  |
| c1     | 1.200      | 1.400          | 0.047                | 0.055 |  |
| D      | 9.910      | 10.250         | 0.390                | 0.404 |  |
| E      | 8.9500     | 9.750          | 0.352                | 0.384 |  |
| E1     | 12.650     | 12.950         | 0.498                | 0.510 |  |
| е      | 2.540      | ) TYP.         | 0.100 TYP.           |       |  |
| e1     | 4.980      | 5.180          | 0.196                | 0.204 |  |
| F      | 2.650      | 2.950          | 0.104                | 0.116 |  |
| Н      | 7.900      | 8.100          | 0.311                | 0.319 |  |
| h      | 0.000      | 0.300          | 0.000                | 0.012 |  |
| L      | 12.900     | 13.400         | 0.508                | 0.528 |  |
| L1     | 2.850      | 3.250          | 0.112                | 0.128 |  |
| V      | 7.500 REF. |                | 0.295 REF.           |       |  |
| Φ      | 3.400      | 3.800          | 0.134                | 0.150 |  |



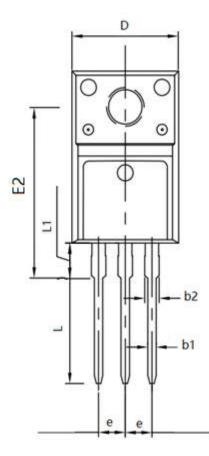
## **TO-263-3L Package Information**

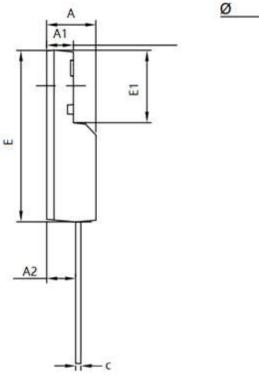


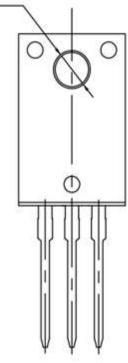
| Sumbal | Dimensions | In Millimeters | Dimensions In Inches |       |  |
|--------|------------|----------------|----------------------|-------|--|
| Symbol | Min.       | Max.           | Min.                 | Max.  |  |
| A      | 4.32       | 4.57           | 0.170                | 0.180 |  |
| A1     | -          | 0.25           |                      | 0.010 |  |
| b      | 0.71       | 0.94           | 0.028                | 0.037 |  |
| b2     | 1.15       | 1.40           | 0.045                | 0.055 |  |
| с      | 0.46       | 0.61           | 0.018                | 0.024 |  |
| c2     | 1.22       | 1.40           | 0.048                | 0.055 |  |
| D      | 8.89       | 9.40           | 0.350                | 0.370 |  |
| D1     | 8.01       | 8.23           | 0.315                | 0.324 |  |
| E      | 10.04      | 10.28          | 0.395                | 0.405 |  |
| E1     | 7.88       | 8.08           | 0.310                | 0.318 |  |
| е      | 2.54       | 2.54 BSC       |                      | BSC   |  |
| L      | 14.73      | 15.75          | 0.580                | 0.620 |  |
| L1     | 2.29       | 2.79           | 0.090                | 0.110 |  |
| L2     | 1.15       | 1.39           | 0.045                | 0.055 |  |
| L3     | 1.27       | 1.77           | 0.050                | 0.070 |  |



# **TO-220F Package Information**







| Symbol | Dimensions In Millimeters |           | Dimension | s In Inches |
|--------|---------------------------|-----------|-----------|-------------|
|        | Min.                      | Max.      | Min.      | Max.        |
| A      | 4.500                     | 4.900     | 0.177     | 0.193       |
| A1     | 2.340                     | 2.740     | 0.092     | 0.108       |
| A2     | 2.560                     | 2.960     | 0.101     | 0.117       |
| b1     | 0.700                     | 0.900     | 0.028     | 0.035       |
| b2     | 1.180                     | 1.580     | 0.046     | 0.062       |
| С      | 0.400                     | 0.600     | 0.016     | 0.024       |
| D      | 9.960                     | 10.360    | 0.392     | 0.408       |
| E      | 15.670                    | 15.970    | 0.617     | 0.629       |
| E1     | 6.500                     | 6.900     | 0.256     | 0.272       |
| E2     | 15.500                    | 16.100    | 0.610     | 0.634       |
| e      | 2.540                     | 2.540 TYP |           | ) TYP       |
| Φ      | 3.080                     | 3.280     | 0.121     | 0.129       |
| L      | 12.640                    | 13.240    | 0.498     | 0.521       |
| L1     | 3.030                     | 3.430     | 0.119     | 0.135       |



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